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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK3140

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1069-0500

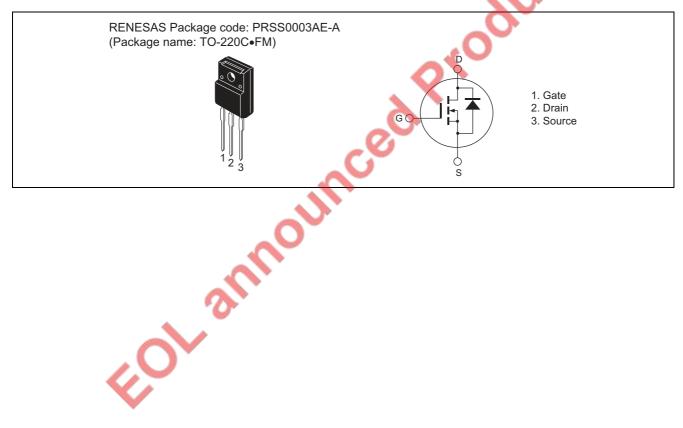
(Previous: ADE-208-767C)

Rev.5.00 Sep 07, 2005

Features

- Low on-resistance $R_{DS(on)} = 6 \text{ m}\Omega \text{ typ.}$
- Low drive current
- 4 V gate drive device can be driven from 5 V source

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

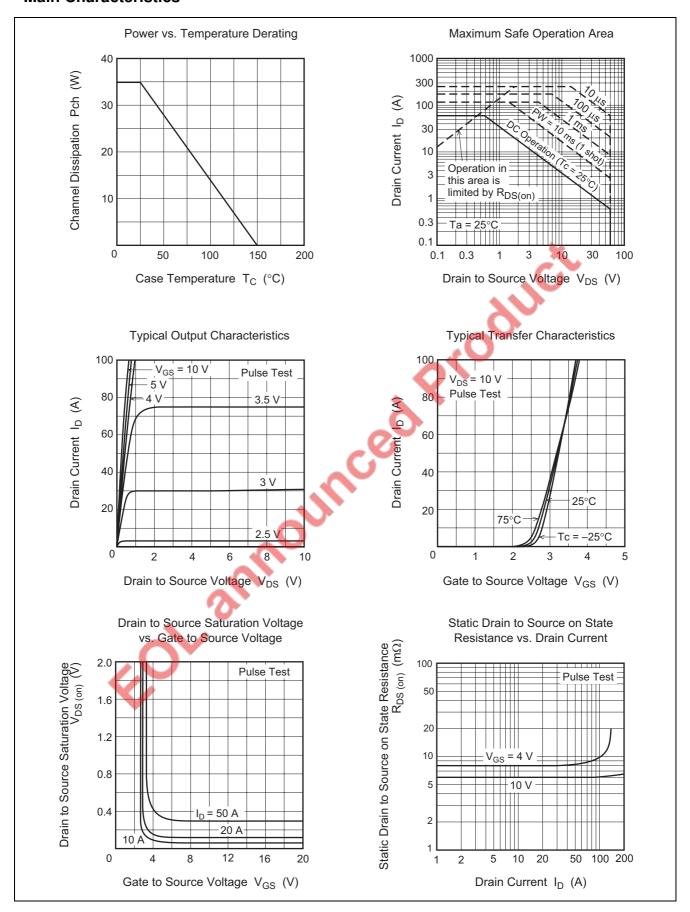
| Item | Symbol | Ratings | Unit |
|--|------------------------------|-------------|------|
| Drain to source voltage | V _{DSS} | 60 | V |
| Gate to source voltage | V _{GSS} | ±20 | V |
| Drain current | I _D | 60 | Α |
| Drain peak current | I _{D(pulse)} Note 1 | 240 | Α |
| Body-drain diode reverse drain current | I _{DR} | 60 | Α |
| Avalanche current | I _{AP} Note 3 | 50 | Α |
| Avalanche energy | E _{AR} Note 3 | 214 | mJ |
| Channel dissipation | Pch Note 2 | 35 | W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | −55 to +150 | °C |

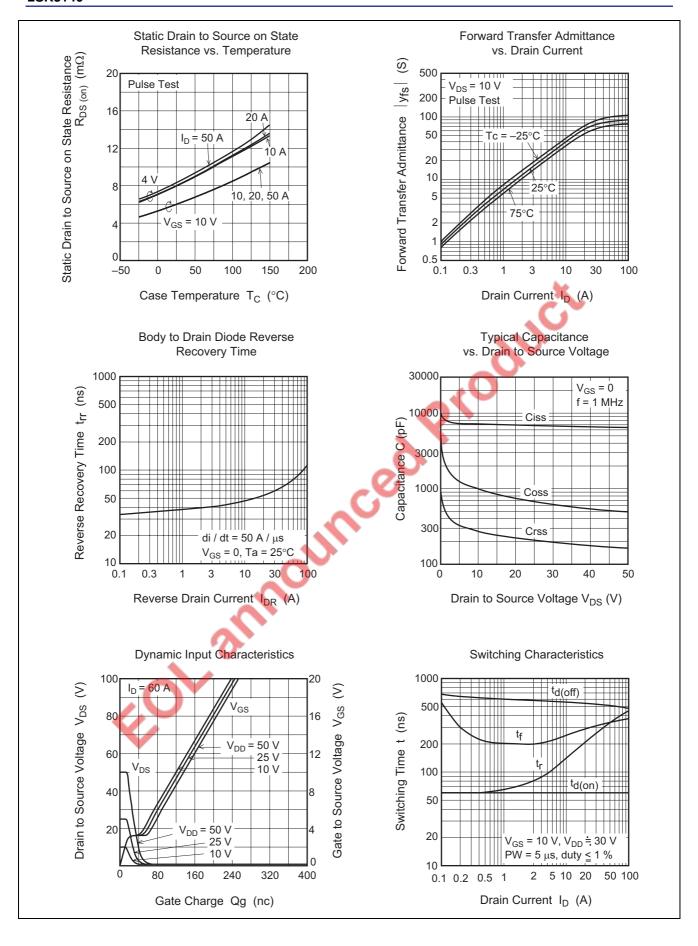
Electrical Characteristics

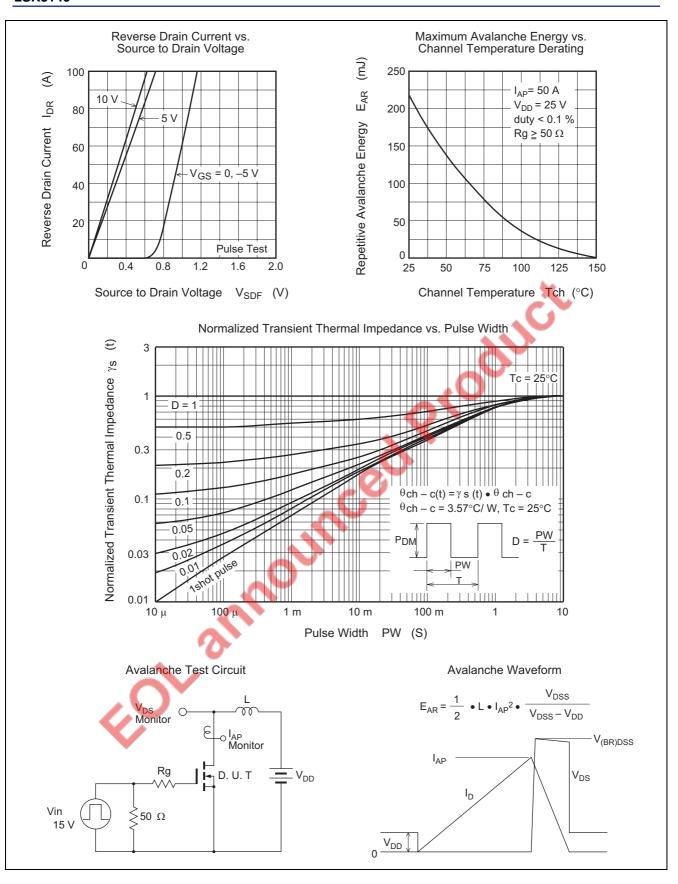
| Storage temperature | | Tstg | | −55 to +150 | | 0 °C | | | |
|--|----------------------|----------|------|-------------|------|--|--|--|--|
| Notes: 1. PW ≤ 10 ∞s, duty cycle ≤ 1% | | | | | | | | | |
| 2. Value at Tc = 25°C | | | | | | | | | |
| 3. Value at Tch = 25°C, Rg ≥ 50 Ω | | | | | | | | | |
| Notes: 1. PW ≤ 10 ∞s, duty cycle ≤ 1% 2. Value at Tc = 25°C 3. Value at Tch = 25°C, Rg ≥ 50 Ω Electrical Characteristics | | | | | | | | | |
| Electrical Characteristics | | | | | | | | | |
| | | | | | | $(Ta = 25^{\circ}C)$ | | | |
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions | | | |
| Drain to source breakdown voltage | V _{(BR)DSS} | 60 | _ | _ | V | $I_D = 10 \text{ mA}, V_{GS} = 0$ | | | |
| Gate to source leak current | I _{GSS} | _ | _ | ±0.1 | ∝A | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$ | | | |
| Zero gate voltage drain current | I _{DSS} | _ | _ | 10 | ∝A | $V_{DS} = 60 \text{ V}, V_{GS} = 0$ | | | |
| Gate to source cutoff voltage | V _{GS(off)} | 1.0 | | 2.5 | V | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$ | | | |
| Static drain to source on state | R _{DS(on)} | _ | 6.0 | 7.5 | mΩ | $I_D = 30 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$ | | | |
| resistance | | | 8.0 | 12 | mΩ | $I_D = 30 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note 4}}$ | | | |
| Forward transfer admittance | y _{fs} | 45 🐗 | 75 | _ | S | $I_D = 30 \text{ A}, \ V_{DS} = 10 \ V^{\text{Note 4}}$ | | | |
| Input capacitance | Ciss | _ | 7100 | | рF | $V_{DS} = 10 \text{ V}, V_{GS} = 0,$ | | | |
| Output capacitance | Coss | | 1000 | | рF | f = 1 MHz | | | |
| Reverse transfer capacitance | Crss |) | 280 | | рF | | | | |
| Total gate charge | Qg | _ | 125 | | nC | $V_{DD} = 25 \text{ V}, V_{GS} = 10 \text{ V},$ | | | |
| Gate to source charge | Qgs | _ | 25 | | nC | I _D = 60 A | | | |
| Gate to drain charge | Qgd | _ | 25 | | nC | | | | |
| Turn-on delay time | $t_{d(on)}$ | _ | 60 | | ns | V_{GS} = 10 V, I_D = 30 A, R_L = 1 Ω | | | |
| Rise time | t _r | _ | 250 | | ns | | | | |
| Turn-off delay time | $t_{d(off)}$ | _ | 540 | _ | ns | | | | |
| Fall time | t _f | _ | 320 | _ | ns | | | | |
| Body-drain diode forward voltage | V_{DF} | _ | 1.0 | | V | $I_F = 60 \text{ A}, V_{GS} = 0$ | | | |
| Body-drain diode reverse recovery time | t _{rr} | _ | 80 | _ | ns | $I_F = 60 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\infty \text{s}$ | | | |
| * * | | | | | | - 1: -: | | | |

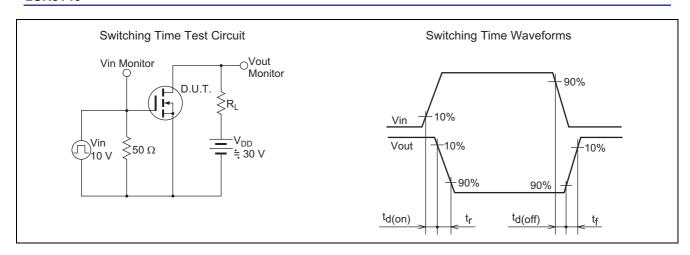
Note: 4. Pulse test

Main Characteristics



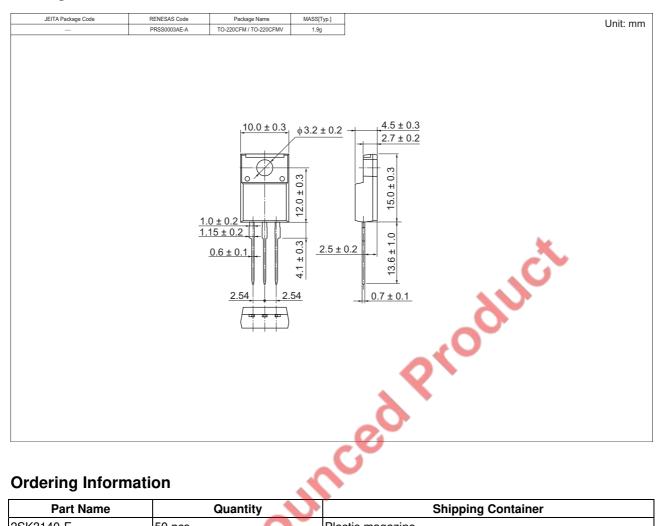








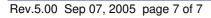
Package Dimensions



Ordering Information

| Part Name | Quantity | V | Shipping Container |
|-----------|----------|---|--------------------|
| 2SK3140-E | 50 pcs | | Plastic magazine |

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